

The listing of claims will replace all prior versions, and listings, of claims in the application:

**Listing of Claims:**

1. (Currently Amended) A light emitting device comprising:  
a thin film transistor on an insulating surface;  
an interlayer insulating film over the thin film transistor;  
an anode over the interlayer insulating film;  
a wiring electrically connected to the thin film transistor and the anode;  
a bank over the wiring and a portion of the anode;  
a first insulating film over the anode and an upper surface of the bank;  
an organic compound layer over the anode with the first insulating film interposed therebetween; and  
a cathode over the organic compound layer.
  
2. (Currently Amended) A light emitting device comprising:  
a thin film transistor on an insulating surface;  
an interlayer insulating film over the thin film transistor;  
an anode over the interlayer insulating film;  
a wiring electrically connected to the thin film transistor and the anode;  
a bank over the wiring and a portion of the anode;  
a first insulating film over the anode and an upper surface of the bank;  
an organic compound layer over the anode with the first insulating film interposed therebetween; and  
a cathode over the organic compound layer,  
wherein the first insulating film is formed from an organic resin film.

3. (Currently Amended) A light emitting device comprising:

a thin film transistor on an insulating surface;

an interlayer insulating film over the thin film transistor;

an anode over the interlayer insulating film;

a wiring electrically connected to the thin film transistor and the anode;

a bank over the wiring and a portion of the anode;

a first insulating film over the anode and an upper surface of the bank;

an organic compound layer over the anode with the first insulating film interposed

therebetween; and

a cathode over the organic compound layer,

wherein the first insulating film is at a film thickness of 1 to 5nm.

4. (Canceled)

5. (Currently Amended) A light emitting device comprising:

a thin film transistor on an insulating surface;

an interlayer insulating film over the thin film transistor;

an anode over the interlayer insulating film;

a wiring electrically connected to the thin film transistor and the anode;

a bank over the wiring and a portion of the anode;

a first insulating film over the anode and an upper surface of the bank;

an organic compound layer over the anode with the first insulating film interposed

therebetween; and

a cathode over the organic compound layer[.].

wherein the anode is formed from indium tin oxide.

6. (Currently Amended) A light emitting device comprising:

a thin film transistor on an insulating surface;

an interlayer insulating film over the thin film transistor;  
an anode over the interlayer insulating film;  
a wiring electrically connected to the thin film transistor and the anode;  
a bank over the wiring and a portion of the anode;  
a first insulating film over the anode and an upper surface of the bank;  
an organic compound layer over the anode with the first insulating film interposed therebetween; and  
a cathode over the organic compound layer;  
wherein the first insulating film is formed from an organic resin film;  
wherein the first insulating film is at a film thickness of 1 to 5nm; and  
wherein the anode is formed from indium tin oxide.

7. (Original) A device according to claim 1, wherein an average surface roughness (Ra) of the anode is in a range of 0.9 nm or less.

8. (Original) A device according to claim 1, wherein an average surface roughness (Ra) of the anode is in a range of 0.85 nm or less.

9. (Original) A device according to claim 1, wherein the interlayer insulating film comprises at least one selected from the group consisting of a silicon oxide film, a silicon nitride oxide film and a silicon oxide nitride film.

10. (Original) A device according to claim 1,  
wherein the bank is processed by a plasma; and  
wherein the bank comprises a hardened film including at least an element selected from the group consisting of hydrogen, nitrogen, halocarbon, hydrogen fluoride, and noble gas.

11. (Withdrawn) A device according to claim 1,  
wherein a second insulating film is formed over the interlayer insulating film; and  
wherein the second insulating film comprises at least one selected from the  
group consisting of a silicon nitride film and a diamond like carbon film.

12. (Original) A device according to claim 1,  
wherein the light emitting device is in combination with an electric device; and  
wherein the electric device is one selected from the group consisting of a display,  
a digital still camera, a notebook type personal computer, a mobile computer, an image  
reproduction apparatus including a recording medium, a goggle type display, a video  
camera and a mobile phone.

13. (Original) A device according to claim 2, wherein an average surface  
roughness (Ra) of the anode is in a range of 0.9 nm or less.

14. (Original) A device according to claim 2, wherein an average surface  
roughness (Ra) of the anode is in a range of 0.85 nm or less.

15. (Original) A device according to claim 2, wherein the interlayer insulating  
film comprises at least one selected from the group consisting of a silicon oxide film, a  
silicon nitride oxide film and a silicon oxide nitride film.

16. (Original) A device according to claim 2,  
wherein the bank is processed by a plasma; and  
wherein the bank comprises a hardened film including at least an element  
selected from the group consisting of hydrogen, nitrogen, halocarbon, hydrogen  
fluoride, and noble gas.

17. (Withdrawn) A device according to claim 2,  
wherein a second insulating film is formed over the interlayer insulating film; and  
wherein the second insulating film comprises at least one selected from the  
group consisting of a silicon nitride film and a diamond like carbon film.

18. (Original) A device according to claim 2,  
wherein the light emitting device is in combination with an electric device; and  
wherein the electric device is one selected from the group consisting of a display,  
a digital still camera, a notebook type personal computer, a mobile computer, an image  
reproduction apparatus including a recording medium, a goggle type display, a video  
camera and a mobile phone.

19. (Original) A device according to claim 3, wherein an average surface  
roughness (Ra) of the anode is in a range of 0.9 nm or less.

20. (Original) A device according to claim 3, wherein an average surface  
roughness (Ra) of the anode is in a range of 0.85 nm or less.

21. (Original) A device according to claim 3, wherein the interlayer insulating  
film comprises at least one selected from the group consisting of a silicon oxide film, a  
silicon nitride oxide film and a silicon oxide nitride film.

22. (Original) A device according to claim 3,  
wherein the bank is processed by a plasma; and  
wherein the bank comprises a hardened film including at least an element  
selected from the group consisting of hydrogen, nitrogen, halocarbon, hydrogen  
fluoride, and noble gas.

23. (Withdrawn) A device according to claim 3,  
wherein a second insulating film is formed over the interlayer insulating film; and  
wherein the second insulating film comprises at least one selected from the  
group consisting of a silicon nitride film and a diamond like carbon film.

24. (Original) A device according to claim 3,  
wherein the light emitting device is in combination with an electric device; and  
wherein the electric device is one selected from the group consisting of a display,  
a digital still camera, a notebook type personal computer, a mobile computer, an image  
reproduction apparatus including a recording medium, a goggle type display, a video  
camera and a mobile phone.

25.-30. (Canceled)

31. (Original) A device according to claim 5, wherein an average surface  
roughness (Ra) of the anode is in a range of 0.9 nm or less.

32. (Original) A device according to claim 5, wherein an average surface  
roughness (Ra) of the anode is in a range of 0.85 nm or less.

33. (Original) A device according to claim 5, wherein the interlayer insulating  
film comprises at least one selected from the group consisting of a silicon oxide film, a  
silicon nitride oxide film and a silicon oxide nitride film.

34. (Original) A device according to claim 5,  
wherein the bank is processed by a plasma; and

wherein the bank comprises a hardened film including at least an element selected from the group consisting of hydrogen, nitrogen, halocarbon, hydrogen fluoride, and noble gas.

35. (Withdrawn) A device according to claim 5,  
wherein a second insulating film is formed over the interlayer insulating film; and  
wherein the second insulating film comprises at least one selected from the group consisting of a silicon nitride film and a diamond like carbon film.

36. (Original) A device according to claim 5,  
wherein the light emitting device is in combination with an electric device; and  
wherein the electric device is one selected from the group consisting of a display, a digital still camera, a notebook type personal computer, a mobile computer, an image reproduction apparatus including a recording medium, a goggle type display, a video camera and a mobile phone.

37. (Original) A device according to claim 6, wherein an average surface roughness (Ra) of the anode is in a range of 0.9 nm or less.

38. (Original) A device according to claim 6, wherein an average surface roughness (Ra) of the anode is in a range of 0.85 nm or less.

39. (Original) A device according to claim 6, wherein the interlayer insulating film comprises at least one selected from the group consisting of a silicon oxide film, a silicon nitride oxide film and a silicon oxide nitride film.

40. (Original) A device according to claim 6,  
wherein the bank is processed by a plasma; and

wherein the bank comprises a hardened film including at least an element selected from the group consisting of hydrogen, nitrogen, halocarbon, hydrogen fluoride, and noble gas.

41. (Withdrawn) A device according to claim 6,  
wherein a second insulating film is formed over the interlayer insulating film; and  
wherein the second insulating film comprises at least one selected from the group consisting of a silicon nitride film and a diamond like carbon film.

42. (Original) A device according to claim 6,  
wherein the light emitting device is in combination with an electric device; and  
wherein the electric device is one selected from the group consisting of a display, a digital still camera, a notebook type personal computer, a mobile computer, an image reproduction apparatus including a recording medium, a goggle type display, a video camera and a mobile phone.

43. (Previously Presented) A device according to claim 1,  
wherein the bank is formed from a resin insulating film.

44. (Previously Presented) A device according to claim 2,  
wherein the bank is formed from a resin insulating film.

45. (Previously Presented) A device according to claim 3,  
wherein the bank is formed from a resin insulating film.

46. (Previously Presented) A device according to claim 5,  
wherein the bank is formed from a resin insulating film.



47. (Previously Presented) A device according to claim 6,  
wherein the bank is formed from a resin insulating film.